8 OUT

7

6

5 0C

8

7

6

5

TPS2051 D OR P PACKAGE

(TOP VIEW)

ΠΟυτ

ΠΟυτ

OUT

OUT

<u>OC</u>

ΠΟυτ

TPS2041 D OR P PACKAGE (TOP VIEW)

GND [

IN 🛛 2

IN 🛛 3

EN [

GND

IN 1 2

IN II 3

EN

1

4

 \cap

1

4

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٠	135-m Ω -Maximum (5-V Input) High-Side	
	MOSFET Switch	

- 500 mA Continuous Current
- Short-Circuit and Thermal Protection
- Overcurrent Logic Output
- Operating Range . . . 2.7 V to 5.5 V
- Logic-Level Enable Input
- 2.5-ms Typical Rise Time
- Undervoltage Lockout
- 10 μA Maximum Standby Supply Current
- Bidirectional Switch
- Available in 8-pin SOIC and PDIP Packages
- Ambient Temperature Range, –40°C to 85°C
- 2-kV Human-Body-Model, 200-V Machine-Model ESD Protection

description

The TPS2041 and TPS2051 power distribution switches are intended for applications where heavy capacitive loads and short circuits are likely to be encountered. The TPS2041 and the TPS2051 are 135-m Ω N-channel MOSFET high-side power switches. Each switch is controlled by a logic enable that is compatible with 5-V logic and 3-V logic. Gate drive is provided by an internal charge pump designed to control the power-switch rise times and fall times to minimize current surges during switching. The charge pump requires no external components and allows operation from supplies as low as 2.7 V.

When the output load exceeds the current-limit threshold or a short is present, the TPS2041 and TPS2051 limit the output current to a safe level by switching into a constant-current mode, pulling the overcurrent (\overline{OC}) logic output low. When continuous heavy overloads and short circuits increase the power dissipation in the switch, causing the junction temperature to rise, a thermal protection circuit shuts off the switch to prevent damage. Recovery from a thermal shutdown is automatic once the device has cooled sufficiently. Internal circuitry ensures the switch remains off until valid input voltage is present.

The TPS2041 and TPS2051 are designed to limit at 0.9-A load. These power distribution switches are available in 8-pin small-outline integrated circuit (SOIC) and 8-pin plastic dual-in-line packages (PDIP) and operate over an ambient temperature range of -40°C to 85°C.

		RECOMMENDED MAXIMUM CONTINUOUS	TYPICAL SHORT-CIRCUIT	PACKAGE	D DEVICES
TA	ENABLE	LOAD CURRENT (A)	CURRENT LIMIT AT 25°C (A)	SOIC (D) [†]	PDIP (P)
-40°C to 85°C	Active low	0.5	0.9	TPS2041D	TPS2041P
-40°C to 85°C	Active high	0.5	0.9	TPS2051D	TPS2051P

AVAILABLE OPTIONS

[†] The D package is available taped and reeled. Add an R suffix to device type (e.g., TPS2041DR)



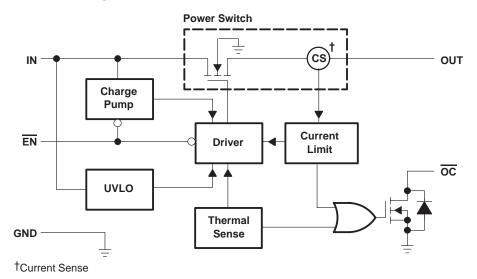
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

This document contains information on products in more than one phase of development. The status of each device is indicated on the page(s) specifying its electrical characteristics.



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TPS2041 functional block diagram



Terminal Functions

	TERMINAI	_						
	NO. D OR P			DECODIDETON				
NAME			1/0	DESCRIPTION				
	TPS2041	TPS2051						
EN	4	-	I	Enable input. Logic low turns on power switch.				
EN	-	4	I	Enable input. Logic high turns on power switch.				
GND	1	1	I	Ground				
IN	2, 3	2, 3	I	Input voltage				
<u>OC</u>	5	5	0	Over current. Logic output active low				
OUT	6, 7, 8	6, 7, 8	0	Power-switch output				



detailed description

power switch

The power switch is an N-channel MOSFET with a maximum on-state resistance of 135 m Ω (V_{I(IN)} = 5 V). Configured as a high-side switch, the power switch prevents current flow from OUT to IN and IN to OUT when disabled. The power switch supplies a minimum of 500 mA per switch.

charge pump

An internal charge pump supplies power to the driver circuit and provides the necessary voltage to pull the gate of the MOSFET above the source. The charge pump operates from input voltages as low as 2.7 V and requires very little supply current.

driver

The driver controls the gate voltage of the power switch. To limit large current surges and reduce the associated electromagnetic interference (EMI) produced, the driver incorporates circuitry that controls the rise times and fall times of the output voltage. The rise and fall times are typically in the 2-ms to 4-ms range.

enable (EN or EN)

The logic enable disables the power switch and the bias for the charge pump, driver, and other circuitry to reduce the supply current to less than 10 μ A when a logic high is present on EN (TPS2041) or a logic low is present on EN (TPS2051). A logic zero input on EN or a logic high on EN restores bias to the drive and control circuits and turns the power on. The enable input is compatible with both TTL and CMOS logic levels.

overcurrent (OC)

The \overline{OC} open drain output is asserted (active low) when an overcurrent or over temperature condition is encountered. The output will remain asserted until the overcurrent or over temperature condition is removed.

current sense

A sense FET monitors the current supplied to the load. The sense FET measures current more efficiently than conventional resistance methods. When an overload or short circuit is encountered, the current-sense circuitry sends a control signal to the driver. The driver in turn reduces the gate voltage and drives the power FET into its saturation region, which switches the output into a constant current mode and holds the current constant while varying the voltage on the load.

thermal sense

An internal thermal-sense circuit shuts off the power switch when the junction temperature rises to approximately 140°C. Hysteresis is built into the thermal sense circuit. After the device has cooled approximately 20°C, the switch turns back on. The switch continues to cycle off and on until the fault is removed.

undervoltage lockout

A voltage sense circuit monitors the input voltage. When the input voltage is below approximately 2 V, a control signal turns off the power switch.



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Input voltage range, V _{I(IN)} (see Note 1)	–0.3 V to 6 V
Output voltage range, VO(OUT) (see Note 1)	–0.3 V to V _{I(IN)} + 0.3 V
Input voltage range, $V_{I(\overline{ENx})}$ or $V_{I(ENx)}$	–0.3 V to 6 V
Continuous output current, Í _{O(OUT)}	internally limited
Continuous total power dissipation	. See Dissipation Rating Table
Operating virtual junction temperature range, T _J	–40°C to 125°C
Storage temperature range, T _{stg}	–65°C to 150°C
Lead temperature soldering 1,6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltages are with respect to GND.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING		
D	725 mW	5.8 mW/°C	464 mW	377 mW		
Р	1175 mW	9.4 mW/°C	752 mW	611 mW		

recommended operating conditions

		TPS2	2041	AX MIN MAX 5.5 2.7 5.5 5.5 0 5.5 500 0 500	2051	UNIT
		MIN	MAX			
Input voltage, VI(IN)		2.7	5.5	2.7	5.5	V
Input voltage, VI(EN) or VI(EN)		0	5.5	0	5.5	V
Continuous output current, IO	OUT	0	500	0	500	mA
Operating virtual junction temperate	ıre, TJ	-40	125	-40	125	°C

electro static discharge (ESD) protection

		UNIT
Human body model MIL-STD-883C	2	kV
Machine model	0.2	kV



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electrical characteristics over recommended operating junction temperature range, $V_{I(IN)}$ = 5.5 V, I_O = rated current, \overline{EN} = 0 V (unless otherwise noted)

power switch

	PARAMETER	TEST COL	NDITIONST	Т	PS2041		Т	PS2051		UNIT
	FARAMETER	TEST CO	DITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
		$V_{I(IN)} = 5 V,$	$T_J = 25^{\circ}C$		80	95		80	95	
		$V_{I(IN)} = 5 V,$	$T_J = 85^{\circ}C$		90	120		90	120	
	Static drain-source on-state	$V_{I(IN)} = 5 V,$	TJ = 125°C		100	135		100	135	mΩ
^r DS(on)	resistance	V _{I(IN)} = 3.3 V,	$T_J = 25^{\circ}C$		85	105		85	105	
		V _{I(IN)} = 3.3 V,	$T_J = 85^{\circ}C$		100	135		100	135	
		V _{I(IN)} = 3.3 V,	TJ = 125°C		115	150		115	150	
		$V_{I(IN)} = 5.5 V,$ $C_{L} = 1 \mu F,$			2.5			2.5		
tr	Rise time, output	$V_{I(IN)} = 2.7 V,$ $C_{L} = 1 \mu F,$	TJ = 25°C, RL = 10 Ω		3			3		ms
+.	Fall time, output	$V_{I(IN)} = 5.5 V,$ $C_{L} = 1 \mu F,$			4.4			4.4		ms
tf		$V_{I(IN)} = 2.7 V,$ $C_{L} = 1 \mu F,$	TJ = 25°C, RL = 10 Ω		2.5			2.5		1115

† Pulse-testing techniques maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.

enable input (EN or EN)

	PARAMETER		TEST CONDITIONS	TPS2041			٦	UNIT		
			TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
V_{IH}	High-level input voltage	e	$2.7 \text{ V} \le \text{V}_{I(IN)} \le 5.5 \text{ V}$	2			2			V
		$4.5 \text{ V} \leq \text{V}_{I(IN)} \leq 5.5 \text{ V}$			0.8			0.8	V	
VIL	Low-level input voltage	;	$2.7 \text{ V} \leq \text{V}_{I(IN)} \leq 4.5 \text{ V}$			0.4			0.4	
	loout ourroot	TPS2041	$\overline{EN} = 0 \vee \text{or } \overline{EN} = V_{I(IN)}$	-0.5		0.5				A
1	Input current	TPS2051	$EN = V_{I(IN)}$ or $EN = 0 V$				-0.5		0.5	μA
ton	Turn-on time		$C_L = 100 \mu\text{F}, \ R_L = 10 \Omega$			20			20	ms
toff	Turn-off time		$C_L = 100 \mu\text{F}, \ R_L = 10 \Omega$			40			40	

current limit

	PARAMETER	TEST CONDITIONS [†]		TPS2041			TPS2051			
FARAMETER		TEST CONDITIONS		TYP	MAX	MIN	TYP	MAX	UNIT	
IOS	Short-circuit output current	$V_{I(IN)} = 5 V$, OUT connected to GND, Device enabled into short circuit, See Figures 6–8, 10–12, 28, and 31.	0.7	0.9	1.1	0.7	0.9	1.1	А	

[†] Pulse-testing techniques maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.



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electrical characteristics over recommended operating junction temperature range, $V_{I(IN)}$ = 5.5 V, I_O = rated current, \overline{EN} = 0 V (unless otherwise noted) (continued)

supply current

PARAMETER		TERT	CONDITIONS		٦	PS2041		Т	PS2051		UNIT		
PARAMETER	TEST CONDITIONS					TYP	MAX	MIN	TYP	MAX	UNIT		
		_	TJ = 25°C	TPS2041		0.015	1						
Supply current, low-level output	No Load	$\overline{EN} = V_{I(IN)}$	$-40^\circ C \leq T_J \leq 125^\circ C$	1952041			10						
		EN = 0 V	TJ = 25°C	TPS2051					0.015	1	μA		
			$-40^\circ C \leq T_J \leq 125^\circ C$	1F 32031						10			
	No Load			<u>EN</u> = 0 V	$T_J = 25^{\circ}C$	TPS2041		80	100				
Supply current,			$-40^\circ C \leq T_J \leq 125^\circ C$	11-02041		100					μA		
high-level output	on OUT		TJ = 25°C	TPS2051					80	100	μΑ		
		EN = VI(IN)	$-40^\circ C \leq T_J \leq 125^\circ C$	1F32031					100				
Leakage current	OUT	$\overline{EN} = V_{I(IN)}$	$-40^\circ C \leq T_J \leq 125^\circ C$	TPS2041		100					۸		
	connected to ground	EN= 0 V	$-40^\circ C \leq T_J \leq 125^\circ C$	TPS2051					100		μA		

undervoltage lockout

PARAMETER	TEST CONDITIONS	Т	PS2041		т	UNIT		
FARAMETER		MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Low-level input voltage		2		2.5	2		2.5	V
Hysteresis	$T_J = 25^{\circ}C$		100			100		mV

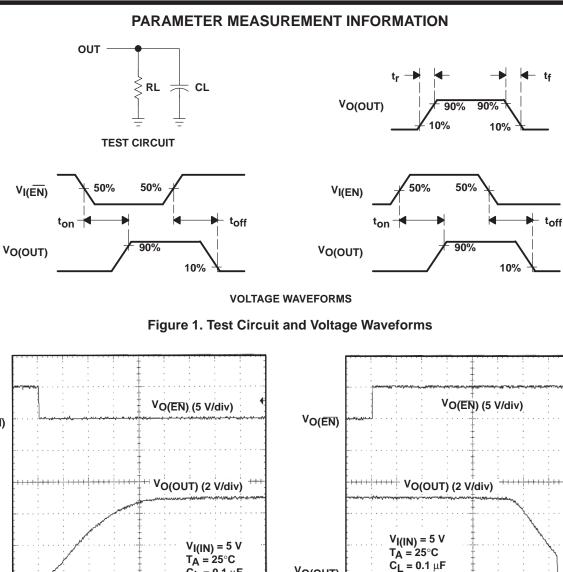
overcurrent OC (see Figure 33)

PARAMETER	TEST CONDITIONS	TPS2041			TPS2051			UNIT
	TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Sink current [†]	$V_{O} = 5 V$			10			10	mA
Output low voltage	$I_{O} = 5 V, V_{OL(OC)}$			0.5			0.5	V
Off-state current [†]	$V_{O} = 5 V$, $V_{O} = 3.3 V$			1			1	μΑ

[†] Specified by design, not production tested.



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V_{O(OUT)}

 $R_L = 10 \Omega$

 t – Time – ms

Figure 3. Turn-off Delay and Fall Time with 0.1-µF Load

C_L = 0.1 μF

 $R_L = 10 \Omega$

t – Time – ms

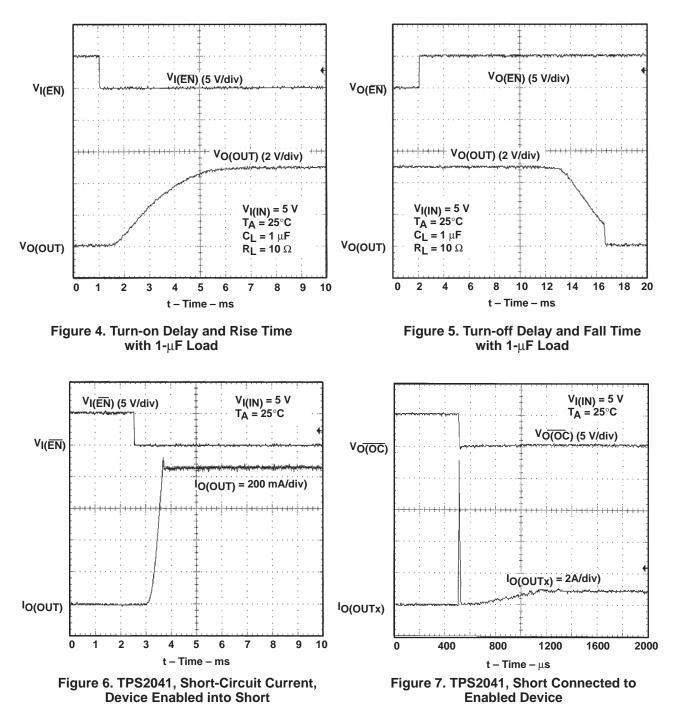
Figure 2. Turn-on Delay and Rise Time with 0.1- μF Load

VI(EN)

VO(OUT)



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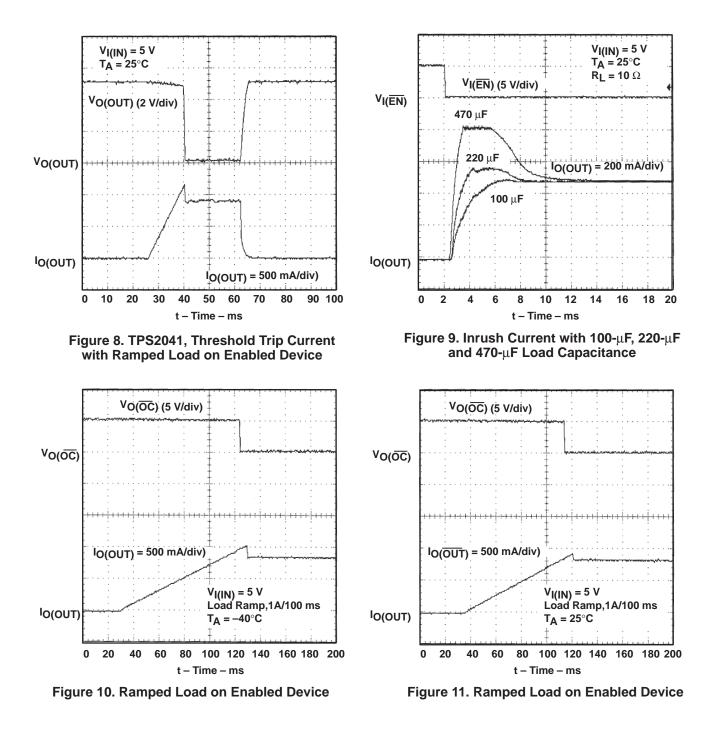


PARAMETER MEASUREMENT INFORMATION



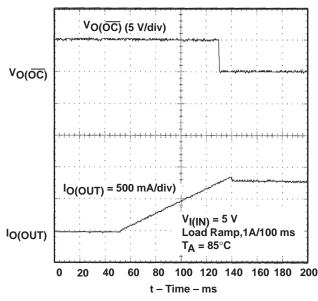
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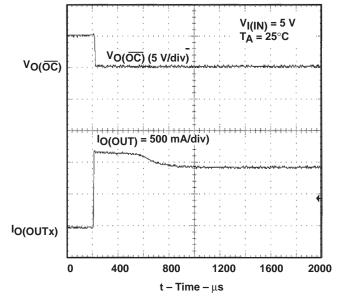
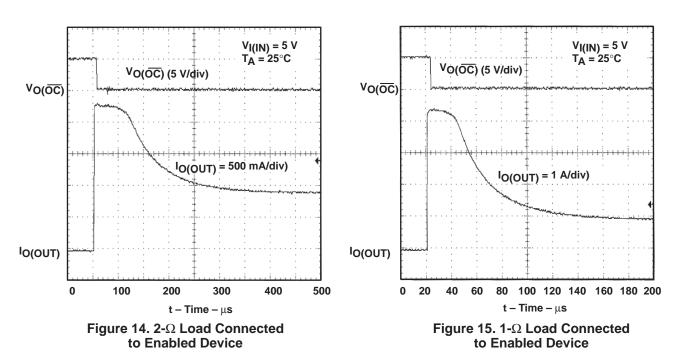


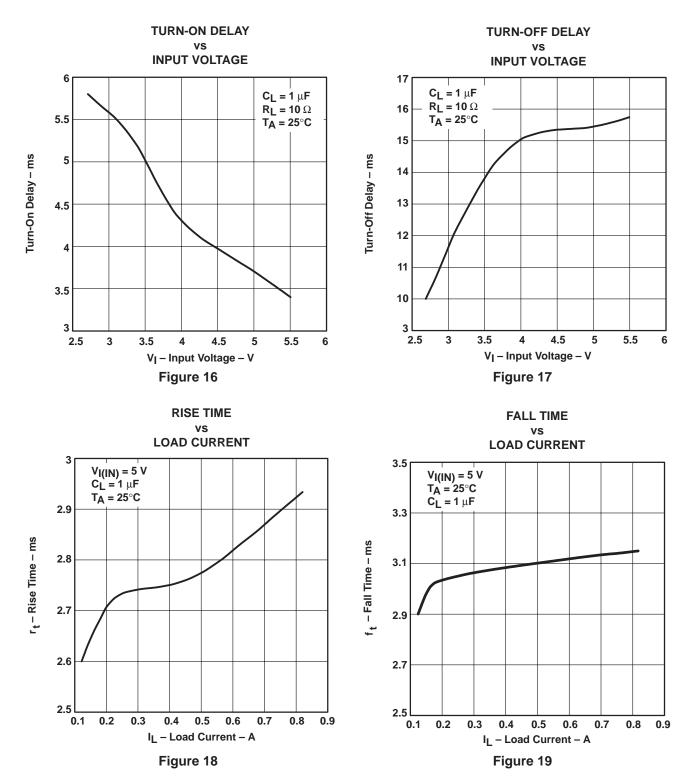
Figure 12. Ramped Load on Enabled Device







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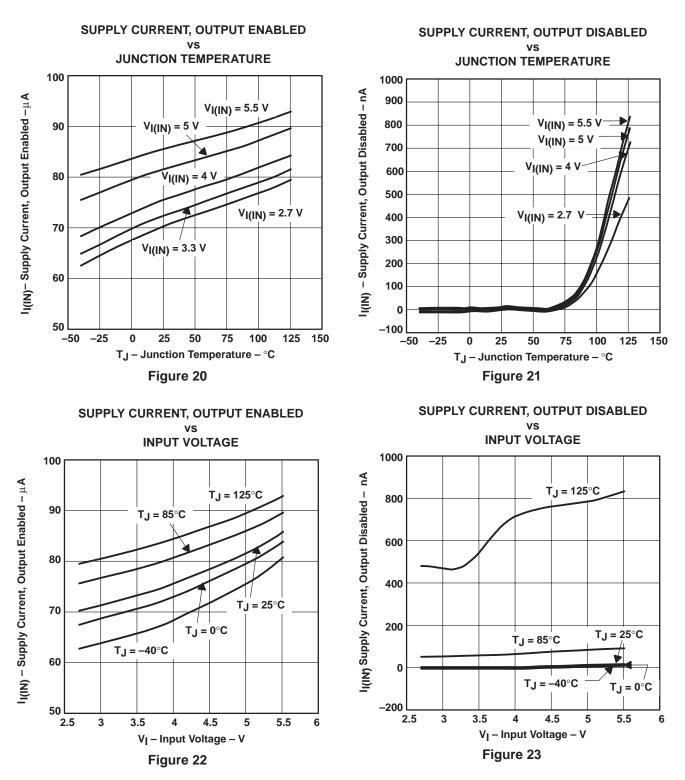


TYPICAL CHARACTERISTICS



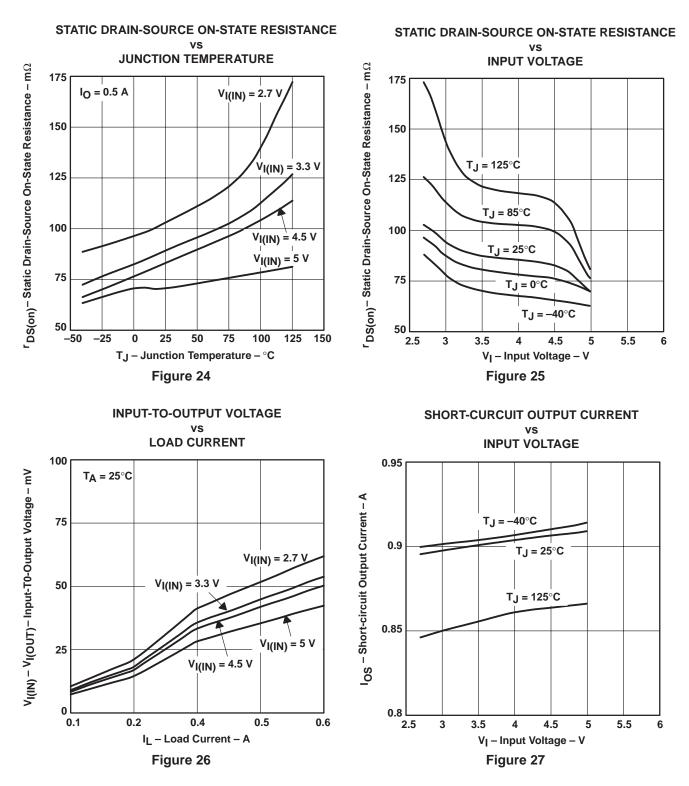
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TYPICAL CHARACTERISTICS





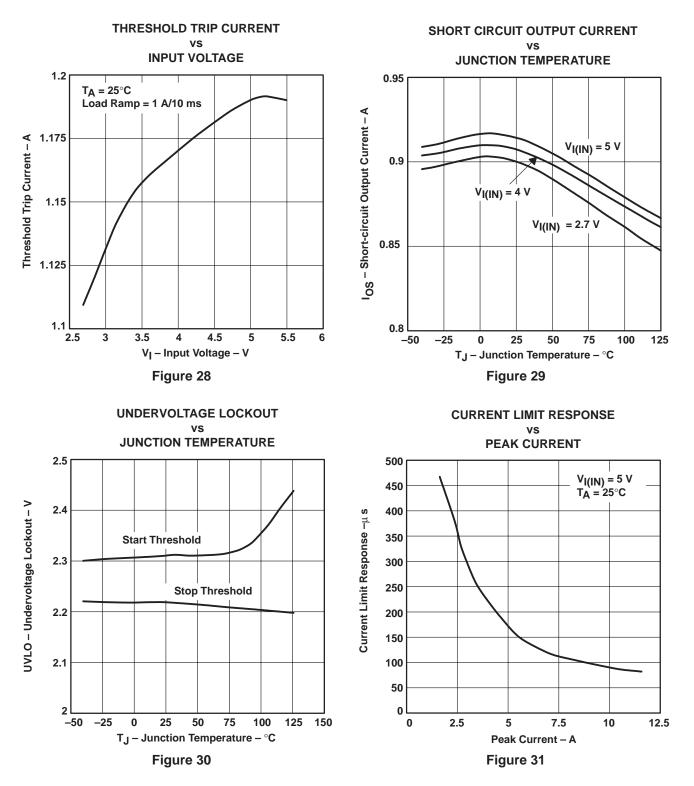
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TYPICAL CHARACTERISTICS



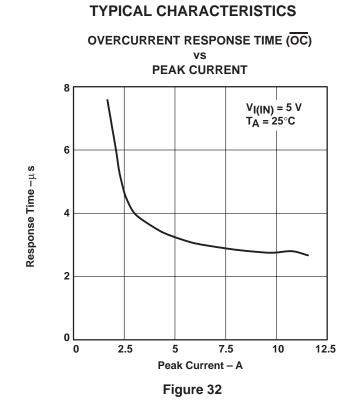
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APPLICATION INFORMATION TPS2041 2,3 **Power Supply** IN 6,7,8 2.7 V to 5.5 V OUT Load **0.1** μ**F 0.1** μF **22** μ**F** 5 OC 4 EN GND 1

Figure 33. Typical Application

power supply considerations

A 0.01- μ F to 0.1- μ F ceramic bypass capacitor between IN and GND, close to the device, is recommended. Placing a high-value electrolytic capacitor on the output pin(s) is also desirable when the output load is heavy. The capacitor reduces power supply transients that may cause ringing on the input. Also, bypassing the output with a 0.01- μ F to 0.1- μ F ceramic capacitor improves the immunity of the device to short-circuit transients.



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APPLICATION INFORMATION

overcurrent

A sense FET is employed to check for overcurrent conditions. Unlike current-sense resistors, sense FETs do not increase the series resistance of the current path. When an overcurrent condition is detected, the device maintains a constant output current and reduces the output voltage accordingly. Complete shutdown occurs only if the fault is present long enough to activate thermal limiting.

Three possible overload conditions can occur. In the first condition, the output has been shorted before the device is enabled or before $V_{I(IN)}$ has been applied (see Figure 6). The TPS2041 and TPS2051 sense the short and immediately switch into a constant-current output.

In the second condition, the short occurs while the device is enabled. At the instant the short occurs, very high currents may flow for a short time before the current-limit circuit can react (see Figure 7). After the current-limit circuit has tripped (reached the overcurrent trip threshold) the device switches into constant-current mode.

In the third condition, the load has been gradually increased beyond the recommended operating current. The current is permitted to rise until the current-limit threshold is reached or until the thermal limit of the device is exceeded (see Figure 8). The TPS2041 and TPS2051 are capable of delivering current up to the current-limit threshold without damaging the device. Once the threshold has been reached, the device switches into its constant-current mode.

OC response

The $\overline{\text{OC}}$ open-drain output is asserted (active low) when an overcurrent or overtemperature condition is encountered. The output will remain asserted until the overcurrent or overtemperature condition is removed. Connecting a heavy capacitive load to an enabled device can cause momentary false overcurrent reporting from the inrush current flowing through the device, charging the downstream capacitor. An RC filter of 500 μ s (see Figure 34) can be connected to the $\overline{\text{OC}}$ pin to reduce false overcurrent reporting. Using low-ESR electrolytic capacitors on the output lowers the inrush current flow through the device during hot-plug events by providing a low impedance energy source, thereby reducing erroneous overcurrent reporting.

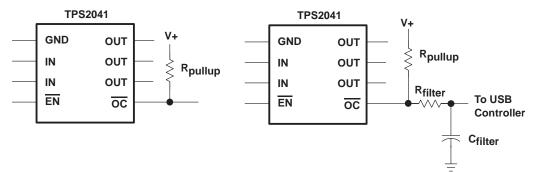


Figure 34. Typical Circuit for OC Pin and RC Filter for Damping Inrush OC Responses



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APPLICATION INFORMATION

power dissipation and junction temperature

The low on-resistance on the n-channel MOSFET allows small surface-mount packages, such as SOIC, to pass large currents. The thermal resistances of these packages are high compared to those of power packages; it is good design practice to check power dissipation and junction temperature. The first step is to find $r_{DS(on)}$ at the input voltage and operating temperature. As an initial estimate, use the highest operating ambient temperature of interest and read $r_{DS(on)}$ from Figure 25. Next, calculate the power dissipation using:

$$P_D = r_{DS(on)} \times l^2$$

Finally, calculate the junction temperature:

$$T_J = P_D \times R_{\theta JA} + T_A$$

Where:

 T_A = Ambient Temperature °C R_{0JA} = Thermal resistance SOIC = 172°C/W, PDIP = 106°C/W

Compare the calculated junction temperature with the initial estimate. If they do not agree within a few degrees, repeat the calculation, using the calculated value as the new estimate. Two or three iterations are generally sufficient to get a reasonable answer.

thermal protection

Thermal protection prevents damage to the IC when heavy-overload or short-circuit faults are present for extended periods of time. The faults force the TPS2041 and TPS2051 into constant current mode, which causes the voltage across the high-side switch to increase; under short-circuit conditions, the voltage across the switch is equal to the input voltage. The increased dissipation causes the junction temperature to rise to high levels. The protection circuit senses the junction temperature of the switch and shuts it off. Hysteresis is built into the thermal sense circuit, and after the device has cooled approximately 20 degrees, the switch turns back on. The switch continues to cycle in this manner until the load fault or input power is removed.

undervoltage lock-out (UVLO)

An undervoltage lockout ensures that the power switch is in the off state at power up. Whenever the input voltage falls below approximately 2 V, the power switch will be quickly turned off. This facilitates the design of hot-insertion systems where it is not possible to turn off the power switch before input power is removed. The UVLO will also keep the switch from being turned on until the power supply has reached at least 2 V, even if the switch is enabled. Upon reinsertion, the power switch will be turned on, with a controlled rise time to reduce EMI and voltage overshoots.

Universal Serial Bus (USB) applications

The Universal Serial Bus (USB) interface is a 12-Mb/s, or 1.5-Mb/s, multiplexed serial bus designed for low-to-medium bandwidth PC peripherals (e.g., keyboards, printers, scanners, and mice). The four-wire USB interface is conceived for dynamic attach-detach (hot plug-unplug) of peripherals. Two lines are provided for differential data, and two lines are provided for 5-V power distribution.

USB data is a 3.3-V level signal, but power is distributed at 5 V to allow for voltage drops in cases where power is distributed through more than one hub across long cables. Each function must provide its own regulated 3.3 V from the 5-V input or its own internal power supply.



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APPLICATION INFORMATION

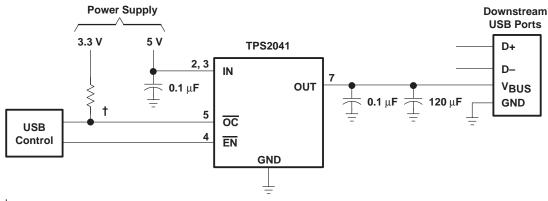
The USB specification defines the following five classes of devices, each differentiated by power-consumption requirements:

- Hosts/self-powered hubs (SPH)
- Bus-powered hubs (BPH)
- Low-power, bus-powered functions
- High-power, bus-powered functions
- Self-powered functions

Self-powered and bus-powered hubs distribute data and power to downstream functions. The TPS2041 and TPS2051 can provide power-distribution solutions for many of these classes of devices.

host/self-powered and bus-powered hubs

Hosts and self-powered hubs have a local power supply that powers the embedded functions and the downstream ports (see Figure 35). This power supply must provide from 5.25 V to 4.75 V to the board side of the downstream connection under full-load and no-load conditions. Hosts and SPHs are required to have current limit protection and must report overcurrent conditions to the USB controller. Typical SPHs are desktop PCs, monitors, printers, and stand-alone hubs.



[†] May need RC Filter (see Figure 34)

Figure 35. One-Port Solution

Bus-powered hubs obtain all power from upstream ports and often contain an embedded function. The hubs are required to power up with less than one unit load. The BPH usually has one embedded function, and power is always available to the controller of the hub. If the embedded function and hub require more than 100 mA on power up, the power to the embedded function may need to be kept off until enumeration is completed. This can be accomplished by removing power or by shutting off the clock to the embedded function. Power switching the embedded function is not necessary if the aggregate power draw for the function and controller is less than one unit load. The total current drawn by the bus-powered device is the sum of the current to the controller, the embedded function, and the downstream ports, and it is limited to 500 mA from an upstream port.



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APPLICATION INFORMATION

low-power bus-powered functions and high-power bus-powered functions

Both low-power and high-power bus-powered functions obtain all power from upstream ports; low-power functions always draw less than 100 mA; high-power functions must draw less than 100 mA at power up and can draw up to 500 mA after enumeration. If the load of the function is more than the parallel combination of 44 Ω and 10 μ F at power up, the device must implement inrush current limiting (see Figure 36).

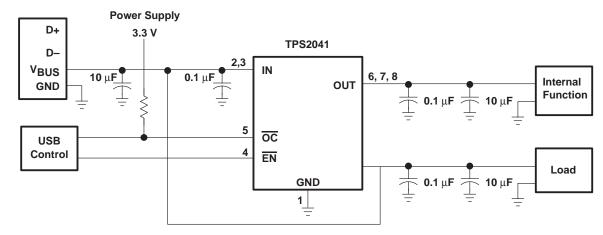


Figure 36. High-Power Bus-Powered Function

USB power-distribution requirements

USB can be implemented in several ways, and, regardless of the type of USB device being developed, several power distribution features must be implemented.

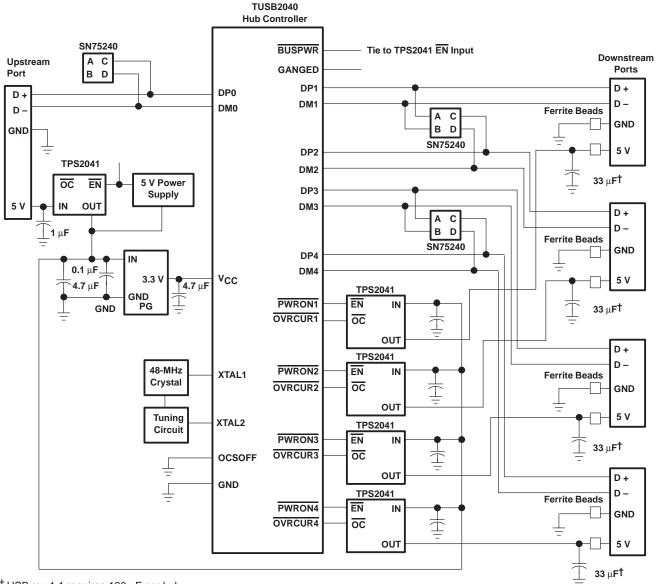
- Hosts/Self-Powered Hubs must:
 - Current-limit downstream ports
 - Report overcurrent conditions on USB V_{BUS}
- Bus-Powered Hubs must:
 - Enable/disable power to downstream ports
 - Power up at <100 mA
 - Limit inrush current (<44 Ω and 10 μ F)
- Functions must:
 - Limit inrush currents
 - Power up at <100 mA

The feature set of the TPS2041 and TPS2051 allows them to meet each of these requirements. The integrated current-limiting and overcurrent reporting is required by hosts and self-powered hubs. The logic-level enable and controlled rise times meet the need of both input and output ports on bus-power hubs, as well as the input ports for bus-power functions (see Figure 37).



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APPLICATION INFORMATION



[†] USB rev 1.1 requires 120 μ F per hub.

Figure 37. Hybrid Self/Bus-Powered Hub Implementation



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APPLICATION INFORMATION

generic hot-plug applications (see Figure 38)

In many applications it may be necessary to remove modules or pc boards while the main unit is still operating. These are considered hot-plug applications. Such implementations require the control of current surges seen by the main power supply and the card being inserted. The most effective way to control these surges is to limit and slowly ramp the current and voltage being applied to the card, similar to the way in which a power supply normally turns on. Due to the controlled rise times and fall times of the TPS2041 and TPS2051, these devices can be used to provide a softer start-up to devices being hot-plugged into a powered system. The UVLO feature of the TPS2041 and TPS2051 also ensures the switch will be off after the card has been removed, and the switch will be off during the next insertion. The UVLO feature guarantees a soft start with a controlled rise time for every insertion of the card or module.

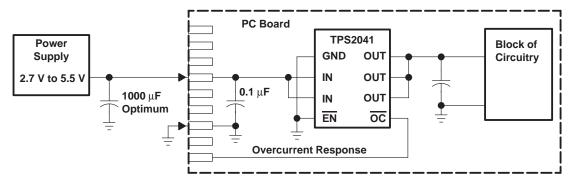


Figure 38. Typical Hot-Plug Implementation

By placing the TPS2041 and TPS2051 between the V_{CC} input and the rest of the circuitry, the input power will reach these devices first after insertion. The typical rise time of the switch is approximately 2.5 ms, providing a slow voltage ramp at the output of the device. This implementation controls system surge currents and provides a hot-plugging mechanism for any device.



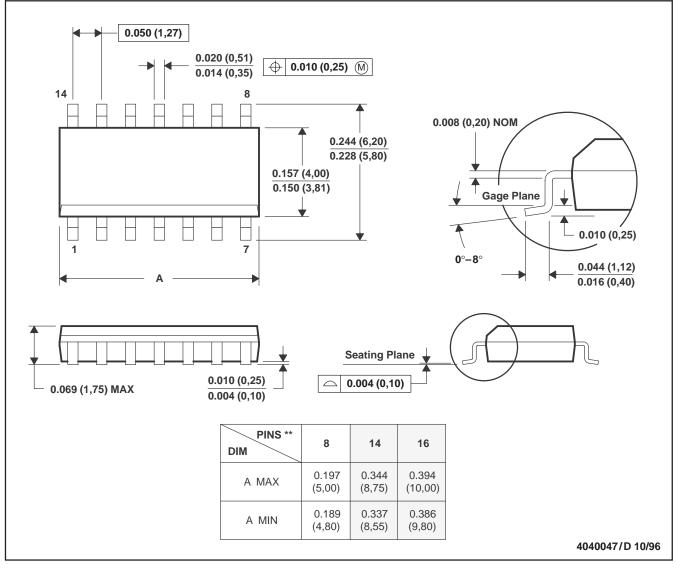
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MECHANICAL DATA

D (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PIN SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012

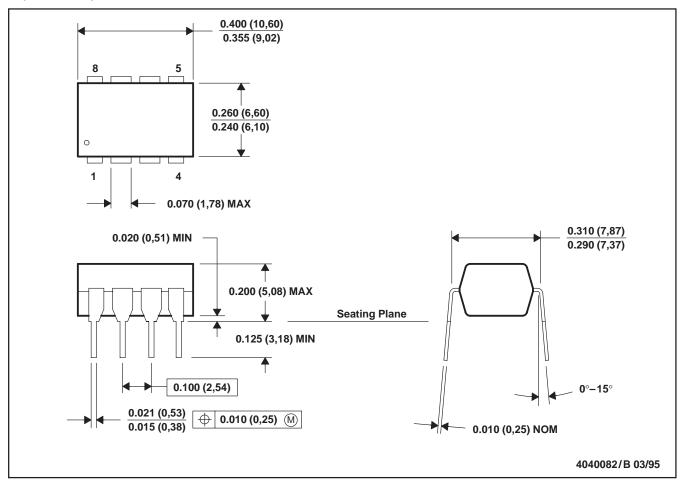


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MECHANICAL DATA

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES: A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001



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